# UK Patent Application (19) GB (11) 2 149 416 A

(43) Application published 12 Jun 1985

- (21) Application No 8427362
- (22) Date of filing 30 Oct 1984
- (30) Priority data
  - (31) 58/208108
- (32) 5 Nov 1983
- (33) JP
- (51) INT CL4 C09K 11/80
- (52) Domestic classification C4S 311 713 731 739 765 78Y U1S 2206 2284 C4S
- (56) Documents cited GB 1600492
- (58) Field of search C4S
- (71) Applicant Sony Corporation (Japan). 7-35 Kitashinagawa-6, Shinagawa-ku, Tokyo, Japan
- (72) Inventors Katsutoshi Ohno Tomohiko Abe Masayoshi Tamura
- (74) Agent and/or Address for Service D Young & Co, 10 Staple Inn, London WC1V 7RD

# (54) Green light emitting phosphors

(57) A green light emitting phosphor suitable for a phosphor screen of a cathode ray tube used as a projecting tube of a projection television receiver is represented by a general formula Y<sub>3</sub>Al<sub>x</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb. The most preferred composition is Y<sub>3</sub>Al<sub>2</sub>Ga<sub>3</sub>O<sub>12</sub>:Tb wherein the Tb density or the molar percentage of Tb/(Y + Tb) is equal to 5 mol %.

FIG.1

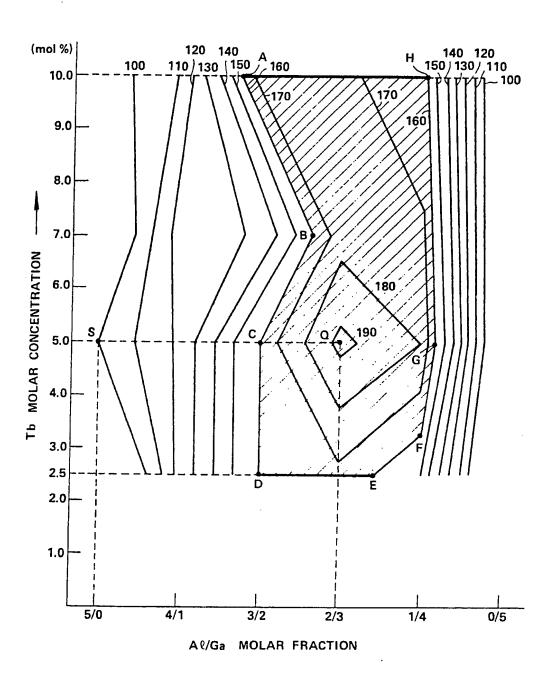
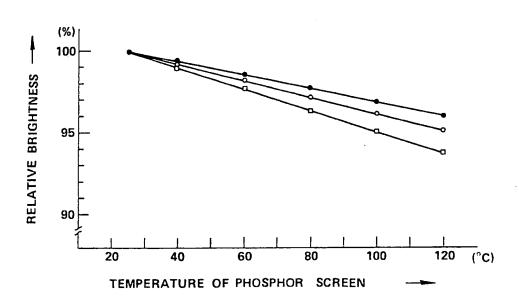


FIG.2



--- Y3 A € 5 O 12 : Tb

Y3 A (3 Ga2 O12 : Tb

0---- Y3 Ga5 O12: Tb

FIG.3

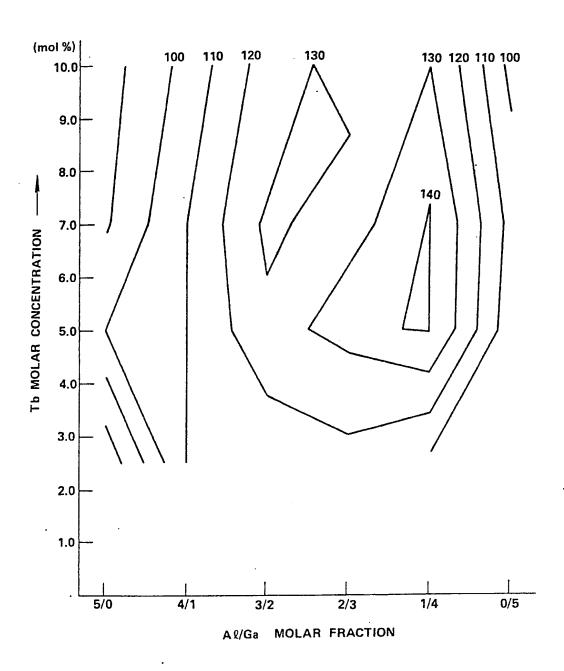
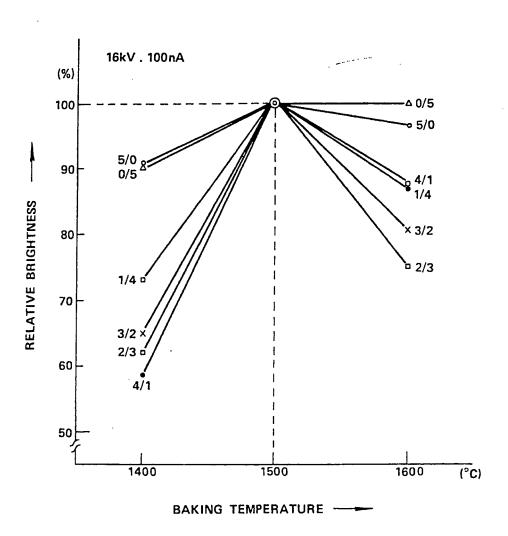


FIG.4



## **SPECIFICATION**

# Green light emitting phosphors

5 This invention relates to green light emitting phosphors. More particularly, but not exclusively, the invention relates to green light emitting phosphors suitable for use in a socalled projection type television receiver. The 10 invention also relates to cathode ray tubes

having a screen incorporating such a green light emitting phosphor.

In general, the phosphor applied to the phosphor screen of a cathode ray tube (CRT) 15 of a projection television receiver is required to emit light of extremely high brightness when excited. As the green phosphor, the composition Gd<sub>2</sub>O<sub>2</sub>S:Tb has been used. However, this phosphor has inferior thermal

20 quenching and current-brightness saturation characteristics. More recently, therefore, the phosphor composition Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>:Tb has been preferred because dissymmetry between the three primary colours (that is, loss of so-called

- 25 white balance) due to thermal quenching can be eliminated, and the phosphor shows higher brightness, so is usable in a projection television receiver. However, for increasing the brightness of the projected image on the
- 30 projection television receiver, it has become necessary to cause the phosphor to emit the light of still higher brightness by exciting the phosphor more strongly by using, for example, a multi-beam electron gun capable
- 35 of increasing the beam current by several times to some tens of times by using several electron beams. In such a case, however, the Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>:Tb phosphor exhibits some brightness saturation. Thus, with the currently em-
- 40 ployed projection type CRT, the current or electron density is approximately 5 to 20 μA/cm<sup>2</sup>, at which the aforementioned composition Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>:Tb used as the green phosphor is still free from brightness saturation. How-
- 45 ever, this is not the case when the beam current (cathode current) is increased further, so that the current density is equal to 20 to 80  $\mu$ A/cm<sup>2</sup> or even to 100  $\mu$ A/cm<sup>2</sup>, whereupon the phosphor becomes subject to bright-
- 50 ness saturation. For this reason, a demand has arisen for a green phosphor which is free from brightness saturation and capable of exhibiting stabilized light emitting characteristics under conditions of a stronger excita-55 tion.

The composition Y<sub>3</sub>Al<sub>2</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb corresponding to the aforementioned composition wherein some Al is replaced by Ga, exhibits brightness saturation characteristics that are

60 superior to those of the composition Y<sub>3</sub>Al-5012: Tb. However, this composition has the drawback that difficulties are encountered in baking or calcining the material for producing the single phase material, and that consider-65 able time and labour are involved in obtaining

the material in powder form, because the phosphor tends to solidify upon baking. In addition, it has been shown that the phosphor may undergo considerable fluctuations in brightness characteristics when fluctuations occur in the baking temperature.

According to the present invention there is provided a phosphor material having a com-

position of  $Y_3AI_xGa_{5-x}O_{12}$ : Tb wherein the AI/75 Ga molar ratio and Tb/(Y + Tb) molar percentage when plotted in a rectangular coordinate system are included within an area defined by a closed loop obtained by connecting points A to H which represent the following values of 80 said molar ratio and said molar percentage, respectively:

	Α	3.3/1.7,	10.0 mol %
	В	2.4/2.6,	7.0 mol %
85	С	3.0/2.0,	5.0 mol %
	D	3.0/2.0,	2.5 mol %
	Ε	1.6/3.4,	2.5 mol %
	F	1.0/4.0,	3.2 mol %
	G	0.9/4.1,	5.0 mol %
90	Н	1.0/4.0,	10.0 mol %

The baking step of the manufacture process of the phosphor material is preferably carried out at 1500°C for obtaining the maximum 95 brightness level.

It is possible with the green phosphor meeting the above conditions to obtain a brightness level about 60 to 90% higher than with the conventional Y3Al5O12:Tb composition un-100 der conditions of stronger excitation, for example, at a current density of 90 μA/cm<sup>2</sup>, the phosphor being still free from brightness

sition can be formulated easily, and the fin-105 ished phosphor material exhibits stable light emitting characteristics with little fluctuation in the brightness level caused by changes in the composition.

saturation. In addition, the starting compo-

The invention will now be described by way 110 of example with reference to the accompanying drawings, in which:

Figure 1 is a graphic chart in which the relative brightness for an excitation voltage of 30 kV and a current density of 90 μA/cm² is 115 plotted with contour lines:

> Figure 2 is a graphic chart in which relative brightness is plotted against increase in the phosphor screen temperature;

Figure 3 is a graphic chart in which the 120 relative brightness for an excitation current of 30 kV and a current density of 10 µA/cm<sup>2</sup> is plotted with contour lines; and

Figure 4 is a graphic chart in which are shown the changes in relative brightness re-125 lated to the baking temperature employed during the preparation of the phosphor.

The preferred embodiment of green light emitting phosphor for a colour television projector and according to the present invention. 130 is a phosphor having the composition Y<sub>3</sub>Al<sub>2</sub>Ga<sub>3</sub>O<sub>12</sub>:Tb, wherein the molar fraction Al/Ga is equal to 2/3 and the molar percentage Tb/(Y + Tb) is equal to 5 mol %. The method of producing the phosphor will now be explained.

#### Example

A powder mixture having the composition:

10 Y<sub>2</sub>O<sub>3</sub> (purity, 4N) 32.18 g Al<sub>2</sub>O<sub>3</sub> (purity, 4N) 10.20 g Ga<sub>2</sub>O<sub>3</sub> (purity, 4N) 28.12 g Tb<sub>4</sub>O<sub>7</sub> (purity, 4N) 2.80 g (wherein purity 4N represents a purity of 15 99.99% or four-nine purity)

is prepared as the starting material necessary for producing the above composition Y<sub>3</sub>Al<sub>2</sub>Ga-3O12:Tb (where the Tb density or concentra-20 tion is equal to 5 mol %). To this mixture is added 3.51 g of BaF2 as flux (reagent of a special grade) and the resulting mixture is dissolved in 70 cc of ethanol as a solvent and is ground in a ball mill. Thus the mixture is 25 charged into an alumina vessel together with alumina balls about 5 mm in diameter and higher than about 99.8% in purity, and ground for about 15 hours at 30 to 100 rpm, for example, 30 rpm. The alumina balls are 30 used in a weight twice or three times that of the starting mixture. The ball-milled starting mixture is filtered or otherwise separated from the alumina balls, dried and freed of ethanol.

The ball-milled and dried materials are
35 charged into a capped alumina crucible of
high purity (for example, higher than 99.8%)
and the cap and the main body of the crucible
are sealed together with a heat-resistance adhesive such as "aron-ceramic D" manufactured and sold by the Toagosei Chemical
Industry Co., Ltd.

The crucible is charged into a furnace and heated to a temperature of 1500°C at a rate of 200°C per hour. It is then kept at this temperature for 2 hours for baking and al-

lowed to cool in the furnace.

measured.

Then, for removing the residual flux from the thus baked phosphor material, it is rinsed in an agitator for 30 to 60 minutes with 1.5N 50 nitric acid which is used at the rate of 10 cc per gram of phosphor.

The phosphor Y<sub>3</sub>Al<sub>2</sub>Ga<sub>3</sub>O<sub>12</sub>:Tb obtained in the above described manner (with a Tb density or concentration of 5 mol %) was used in 55 the preparation of a CRT for a colour television projector (projector tube) and its brightness and temperature characteristics were

In a similar manner, various samples of 60 Y<sub>3</sub>Al<sub>x</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb phosphor with the molar fraction Al/Ga in the range from 5/0 to 0/5 and the molar percentage Tb/(Y + Tb) in the range from 2.5 to 10.0 mol %, were prepared and used in the projector tube, and the brightness and temperature characteristics of these various samples were also measured.

Fig. 1 shows the relative brightness of the phosphor Y3Al5O12:Tb (with a Tb density or concentration of 5 mol %), with the reference 70 brightness being 100, the exciting voltage of the associated projection tubes being 30 kV. and the cathode current lk for the raster size of 100 cm<sup>2</sup> being 9.0 mA (with the current density being 90 µA/cm<sup>2</sup>). In the graphic 75 chart shown in Fig. 1, the Al/Ga molar ratio is plotted on the abscissa and the Tb density or concentration or mol % of Tb/(Y + Tb) is plotted on the ordinate. In this graphic chart, a point S represents the Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>:Tb which 80 gives the aforementioned brightness reference with the Tb density or concentration being 5 mol %. The solid broken lines in the chart represent equi-brightness lines connecting the

points of equal relative brightness in the same 85 manner as the contour lines. The numeral affixed to each broken line designates the relative brightness corrected for the luminosity factor.

It is seen from this figure that the relative brightness is changed from 100 to a higher level of 190 although the exciting condition (voltage of 30 kV and current density of 90 μA/cm²) remains the same. It is at a point Q with the Al/Ga ratio being 2/3 (the phosphor composition thus being Y<sub>3</sub>Al<sub>2</sub>Ga<sub>3</sub>O<sub>12</sub>:Tb) and the Tb density or concentration being at or near 5 mol %, that the value of the relative brightness reaches a maximum of 190 which is most preferred as the phosphor for the 100 television projector. It is in the area shown by

hatching in the AI/Ga ratio-Tb density coordinate system and having a relative brightness level which is higher than 160 that the phosphor may safely be used in the television projector. The aforementioned area with the relative brightness higher than 160 and with the pitch of the equi-brightness lines becom-

ing larger is preferred because, in the area of denser equi-brightness lines, for example, in 110 the area with the Al/Ga ratio in the range of 1/4 to 0/5, the slightest change in the Al/Ga ratio causes drastic changes in brightness so that the starting material would have

to be formulated with the utmost accuracy,
115 and difficulties would be presented in obtaining uniform brightness. For this reason, the
area in the chart with the relative brightness
higher than 160 and with larger equi-brightness line intervals from one another in the

120 drawing is preferred.

A Tb density or concentration lower than 2.5 mol % is also not preferred because then the light emitted by the phosphor would be more diluted with white and would not be

balanced with the red and blue light, so there would be loss of white balance. With the Tb density or concentration higher than 10 mol %, it is impossible to elevate the value of relative brightness further. Moreover, terbium
(Tb) is expensive and therefore it would be

impractical to use the material in more than the required amounts because of the increased manufacturing costs. In addition, the value of relative brightness reaches its maximum at or near the Tb density or concentration of 5.0 mol %. For this reason the upper limit for the Tb density or concentration has been selected to be 10.0 mol %.

To summarize, the phosphor with the com10 position Y<sub>3</sub>Al<sub>x</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb whose Al/Ga ratio and Tb density or concentration are included within an octagon defined by connecting the points A to H in the chart of Fig. 1, excluding the boundary line, is most suitable as the 15 phosphor for a television projector. The Al/Ga ratio and Tb density or concentration or Tb/(Y + Tb) molar percentage for the points A to H are given in the Table below.

## 20 TABLE

35

25		Al/Ga molar ratio	Tb density (mol %)
25	$\overline{A}$	3.3/1.7	10.0
	В	2.4/2.6	7.0
	С	3.0/2.0	5.0
	D	3.0/2.0	2.5
30	Ε	1.6/3.4	2.5
	F	1.0/4.0	3.2
	G	0.9/4.1	5.0
	Н	1.0/4.0	10.0

In particular, the area centred about a point Q in Fig. 1 with the Al/Ga ratio of 2/3 and the Tb density or concentration of 5.0 mol %, and showing only gentle changes in bright-40 ness, and hence the phosphor with, for example, a composition Y<sub>3</sub>Al<sub>x</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb with

the Al/Ga ratio in the range of 2.5/2.5 to 1.5/3.5 and with the Tb density in the range of 3.5 to 10.0 mol %, are most preferred.

Under conditions of stronger excitation such as 30 kV for electrical voltage and 90  $\mu$ A/cm² for current density, the CRT phosphor screen of the green phosphors for the television projector reaches the temperature of 80 to 100°C

50 even when the screen is cooled by liquid cooling as currently employed for a television projector. Thus it becomes necessary to consider the problem of thermal quenching. Referring to Fig. 2, there are shown changes in

55 relative brightness caused by the increased phosphor screen temperature. Thus the relative brightness of three different kinds of phosphor, namely Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>:Tb, Y<sub>3</sub>Al<sub>3</sub>Ga-2O<sub>12</sub>:Tb and Y<sub>3</sub>Ga<sub>5</sub>O<sub>12</sub>:Tb are shown with the

2012:10 and 13 das 012:10 are shown with the brightness value for the phosphor screen temperature of 25°C being 100% for these three phosphors. It is seen from this figure that, while the relative brightness of these phosphors is lowered gradually with increase in the 65 phosphor screen temperature, the amount of

decrease in the relative brightness is not higher than 3.0 to 5.0%, which is acceptable in practice.

In Fig. 3, the values of relative brightness 70 are plotted in a coordinate system of Al/Ga ratio-Tb density for the excitation voltage of 30 kV and the cathode current of 1.0 mA, and thus for the current density of 10 µA/cm<sup>2</sup> with a raster size of 100 cm<sup>2</sup>. The various 75 values of relative brightness of the phosphor samples are plotted by equi-brightness lines with the brightness for the Y3Al5O12:Tb under the same exciting conditions being used as reference brightness (100). It is seen from this figure that the area with the relative brightness higher than 120 and especially higher than 130 or 140 is generally coincident with the area of relative brightness higher than 160 for the aforementioned stronger state of

85 excitation shown in Fig. 1 (with the electrical voltage of 30 kV and the current density of 90 μA/cm²).

Fig. 4 shows relative brightness of several samples of green phosphors for baking temperatures of 1400°C, 1500°C and 1600°C employed at the time of manufacture of the phosphor samples, with the relative brightness for the baking temperature of 1500°C being used as reference brightness (100%). In this 95 figure, the relative brightness is shown of the

six phosphor samples with the molar ratio of AI/Ga in the composition of Y<sub>3</sub>AI<sub>x</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb being 0/5, 1/4, 2/3, 3/2, 4/1 and 5/0. It is seen from the figure that the brightness 100 becomes a maximum with the baking temper-

ature of 1500°C for the samples except the one with the AI/Ga molar ratio equal to 0/5. Thus it is preferred that, in the manufacture of the green phosphor, the baking temperature 105 of 1500°C be employed and the rate of

temperature elevation or retention time at the baking temperature be also selected as set forth in the above Example.

In addition, as disclosed in our copending 110 Patent Application No. 8227684 (serial No. 2 106 924) it is preferred that, immediately after baking, the phosphor be freed of residual flux (BaF<sub>2</sub>) by washing with an acid or alkali in order to avoid "burning" of the phosphor.

115 It is to be noted that the present invention is not limited to the above described embodiments, but may comprise various modifications. For example, BaCl<sub>2</sub> or a mixture thereof with BaF<sub>2</sub> may be used as the flux for the

preparation of the phosphor. These fluxes may be used in any suitable amount different from the value given in the above Example. In addition, an aqueous solution of sodium hydroxide or hydrochloric acid may be employed 125 in place of nitric acid for washing the baked

phosphor for removing the residual solvent.

It is seen from the foregoing that the em-

bodiment of green phosphor for a television projector and according to the present invention is free of brightness saturation and sub-

ject to only negligible thermal quenching even when the current density in the projector tube or CRT is increased to 20 μA/cm² to 80 μA/cm² or even to 100 μA/cm². Thus a projection CRT with extremely high brightness can be realized with the use of a multi-beam electron gun. Moreover, the phosphor is not affected in brightness by small fluctuations in the mixture ratio of the starting composition.

10 In addition, the phosphor is simple to manufacture and exhibits stable light emitting characteristics.

#### **CLAIMS**

1. A phosphor material having a composition of Y<sub>3</sub>Al<sub>x</sub>Ga<sub>5-x</sub>O<sub>12</sub>:Tb wherein the Al/Ga molar ratio and Tb/(Y + Tb) molar percentage when plotted in a rectangular coordinate system are included within an area defined by a closed loop obtained by connecting points A to H which represent the following values of said molar ratio and said molar percentage, respectively:

25	Α	3.3/1.7,	10.0 mol %
	В	2.4/2.6,	7.0 mol %
	С	3.0/2.0,	5.0 mol %
	D	3.0/2.0,	2.5 mol %
	E	1.6/3.4,	2.5 mol %
30	F	1.0/4.0,	3.2 mol %
	G	0.9/4.1,	5.0 mol %
	H	1.0/4.0,	10.0 mol %.

- A phosphor material according to claim
   1 wherein said phosphor material is baked at a temperature of 1500°C at the time of manufacture.
- A phosphor material according to claim 2 wherein said phosphor material is heated to 40 said temperature of 1500°C at the rate of 200°C per hour and kept at the temperature for two hours for baking.
- A phosphor material substantially as hereinbefore described with reference to the 45 Example.
  - 5. A cathode ray tube having a screen incorporating a phosphor material according to any one of the preceding claims.

Printed in the United Kingdom for Her Majesty's Stationery Office, Dd 8818935, 1985, 4235. Published at The Patent Office, 25 Southampton Buildings, London, WC2A 1AY, from which copies may be obtained.